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REPLY UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP

AMENDMENT TRANSMITTAL LETTER

Docket No.
1248-0673P

Application No.
10/668,186-Conf. #4125

Filing Date
September 24, 2003

Examiner
L. M. Schillinger

Art Unit
2813

Applicant(s): Yutaka TAKAFUJI et al.

Invention: SINGLE-CRYSTAL SILICON SUBSTRATE, SOI SUBSTRATE, SEMICONDUCTOR
DEVICE, DISPLAY DEVICE, AND MANUFACTURING METHOD OF SEMICONDUCTOR
DEVICE

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Transmitted herewith is an amendment in the above-identified application.

The fee has been calculated and is transmitted as shown below.

CLAIMS AS AMENDED					
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
Total Claims	57	- 57 =		x	
Independent Claims	14	- 14 =		x	
Multiple Dependent Claims (check if applicable) <input type="checkbox"/>					
Other fee (please specify):					
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT:					0.00

☒ Large Entity

☐ Small Entity

☒ No additional fee is required for this amendment.

☐ Please charge Deposit Account No. _____ in the amount of \$ _____.
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Dated: September 14, 2005

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Docket No.: 1248-0673P
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Yutaka TAKAFUJI et al.

Application No.: 10/668,186

Confirmation No.: 4125

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Art Unit: 2813

For: SINGLE-CRYSTAL SILICON SUBSTRATE,
SOI SUBSTRATE, SEMICONDUCTOR
DEVICE, DISPLAY DEVICE, AND
MANUFACTURING METHOD OF
SEMICONDUCTOR DEVICE

Examiner: L. M. Schillinger

REPLY AFTER FINAL ACTION (37 C.F.R. SECTION 1.116)

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Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated June 27, 2005, please amend the above-identified
U.S. patent application as follows:

Remarks/Arguments begin on page 2 of this paper.